

Simulation of Type-II Quantum Well Photodetectors

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Applicable Models and Features

Input command looping technique to set up 150 pairs of coupled type-II MQW.

Type-II MQW optical gain/absorption spectrum from complex-MQW optical gain model.

Design of absorption spectrum by adjusting type-II band alignments.

Effective mini-band model based on quantum mechanical calculation.



Tutorial example

* Structure similar to

R. Sidhu, N. Duan, J. C. Campbell, and A. L. Holmes, Jr.,
"A 2.3um CUTOFF WAVELENGTH PHOTODIODE ON InP USING LATTICE-MATCHED GalnAs-GaAsSb TYPE-II QUANTUM WELLS,"
2005 International Conference an Indium Phosphide and Related Materials, p. 148, 2005.

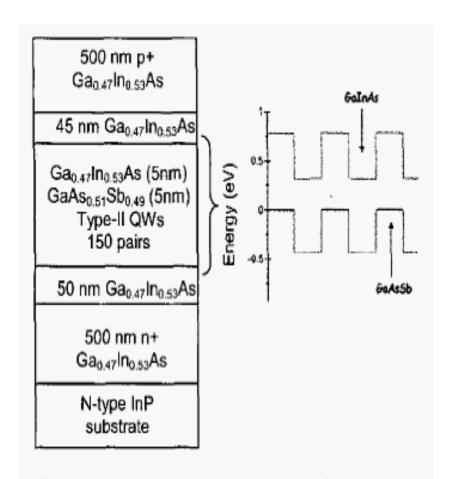
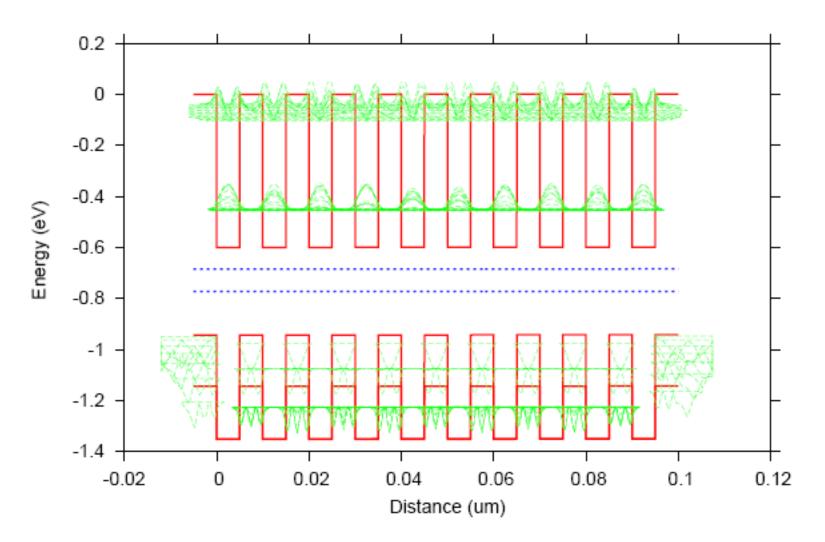


Figure 1. Schematic device structure and band lineup between GalnAs-GaAsSb

^{*} Key adjustable parameters: bandoffset and mobility.

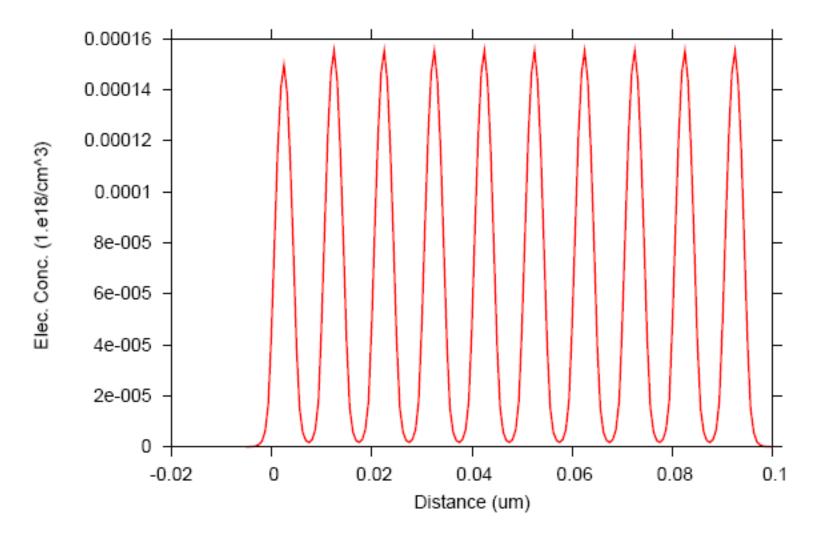
Type-II QWPD: band structure design







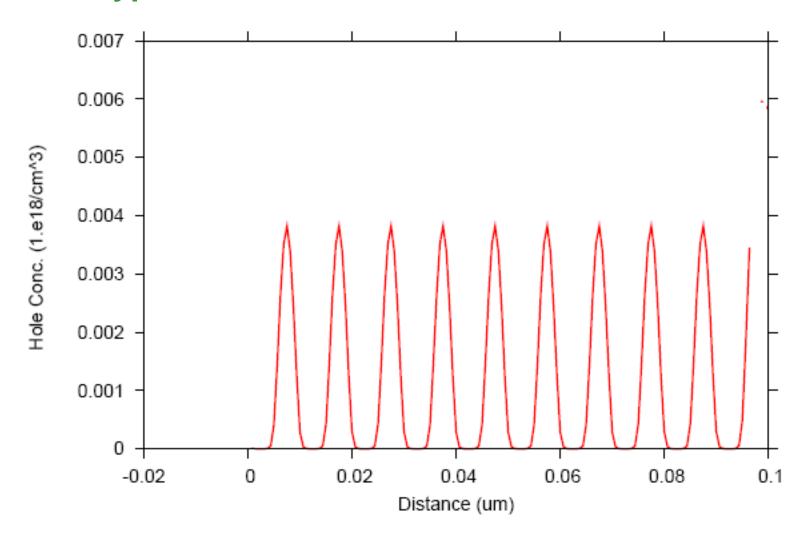
Type-II QWPD: electron densities



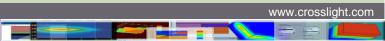




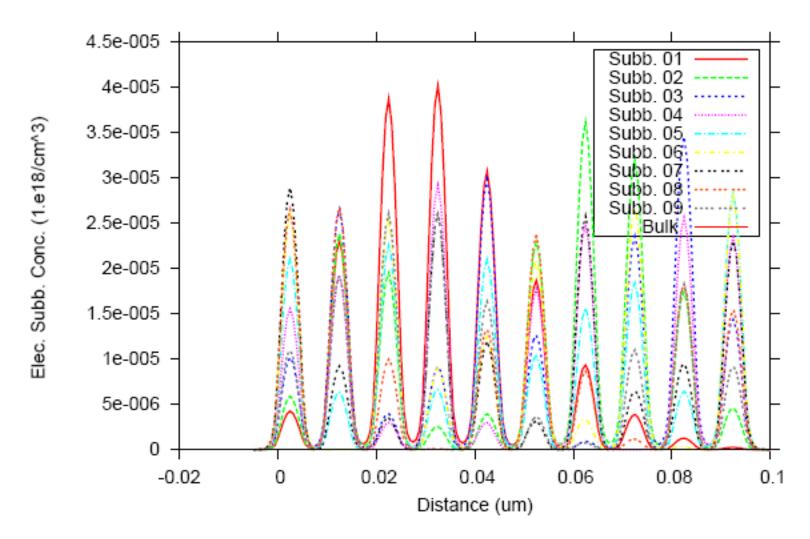
Type-II QWPD: hole densities



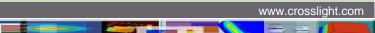




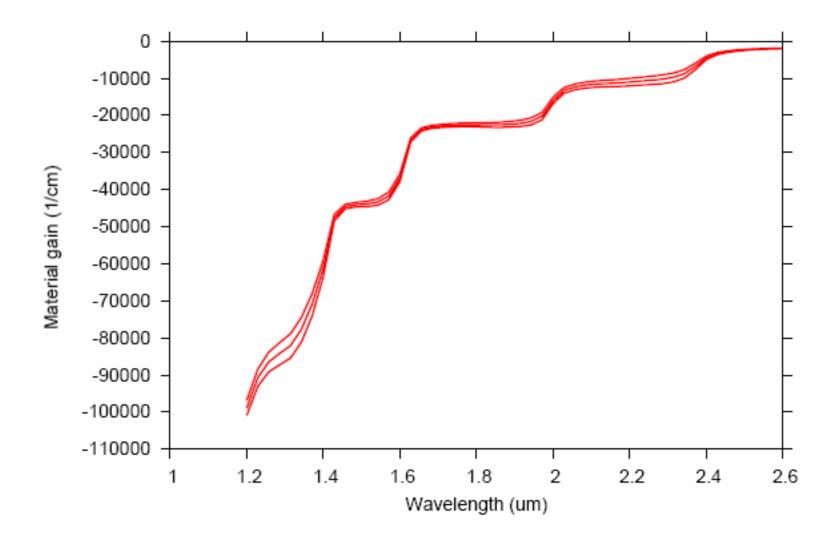
Type-II QWPD: electron subbands







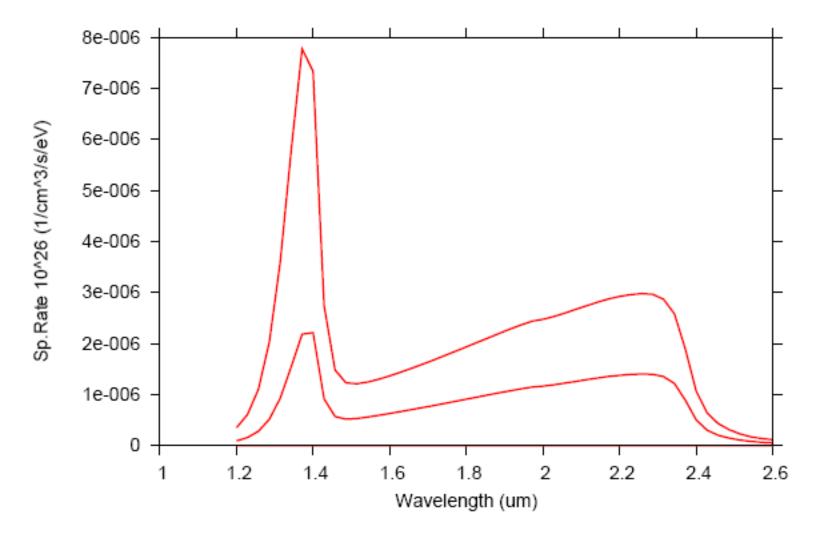
Type-II QWPD: optical gain or -absorption







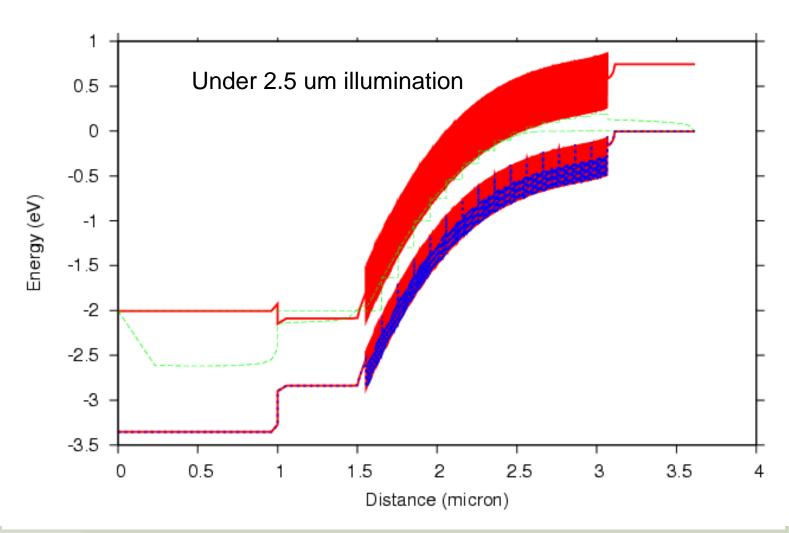
Type-II QWPD: spontaneous emission







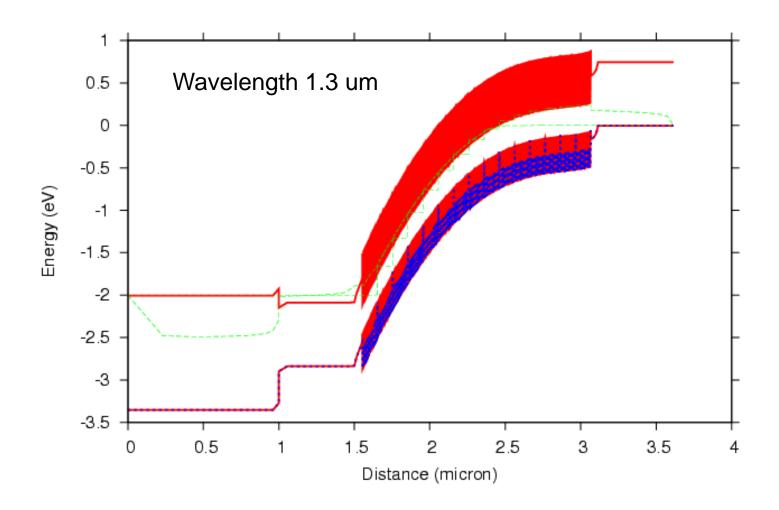
Type-II QWPD: band diagram at 2 Volt



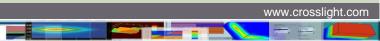




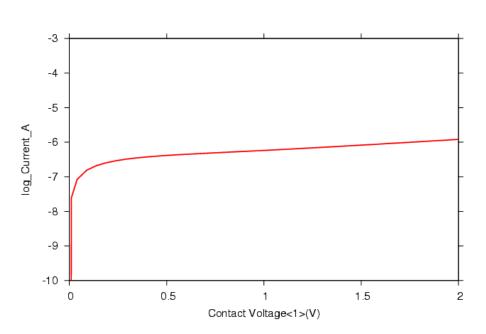
Type-II QWPD: band diagram at 2 Volt







Type-II QWPD: dark current



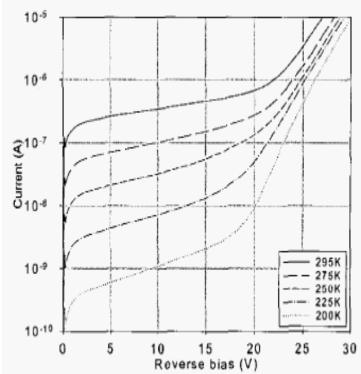
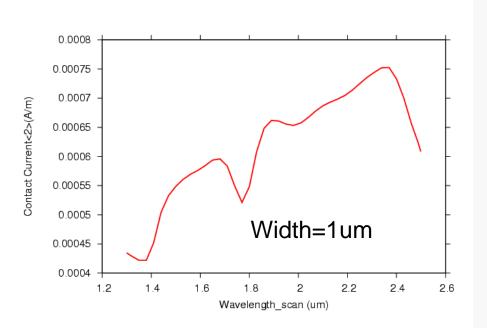


Figure 2. Dark current vs. voltage from a 64µm diameter device, measured at 200K, 225K, 250K, 275K, and 295K.





Type-II QWPD: current response



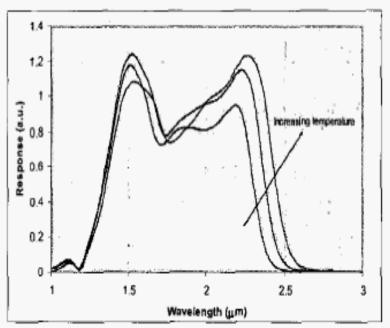
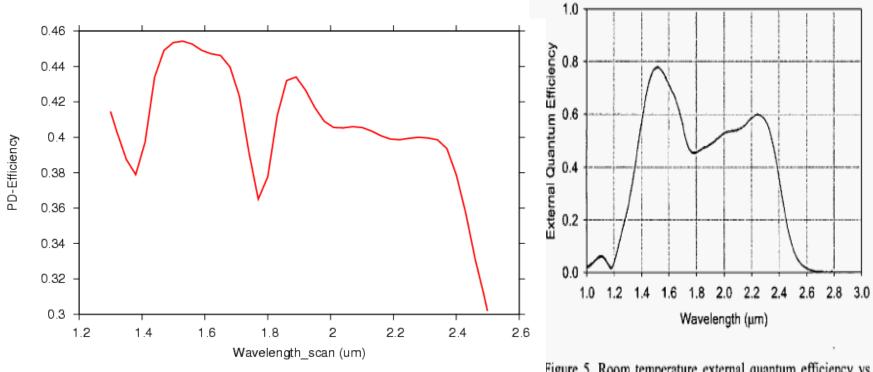


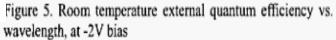
Figure 3. Normal incidence photoresponse at 200K, 250K, and 295K, measured at -2V bias.





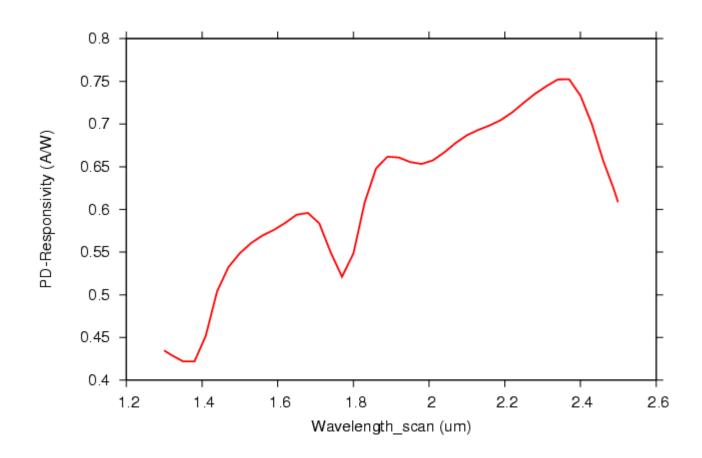
Type-II QWPD: external efficiency







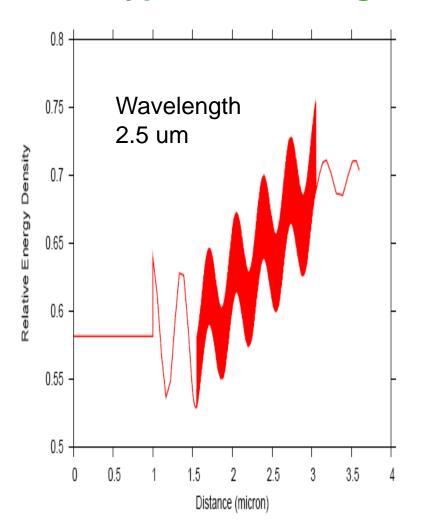
Type-II QWPD: responsivity

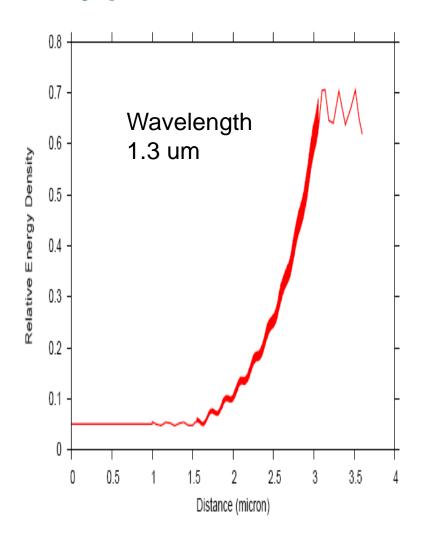




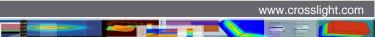


Type-II QWPD: light intensity profiles

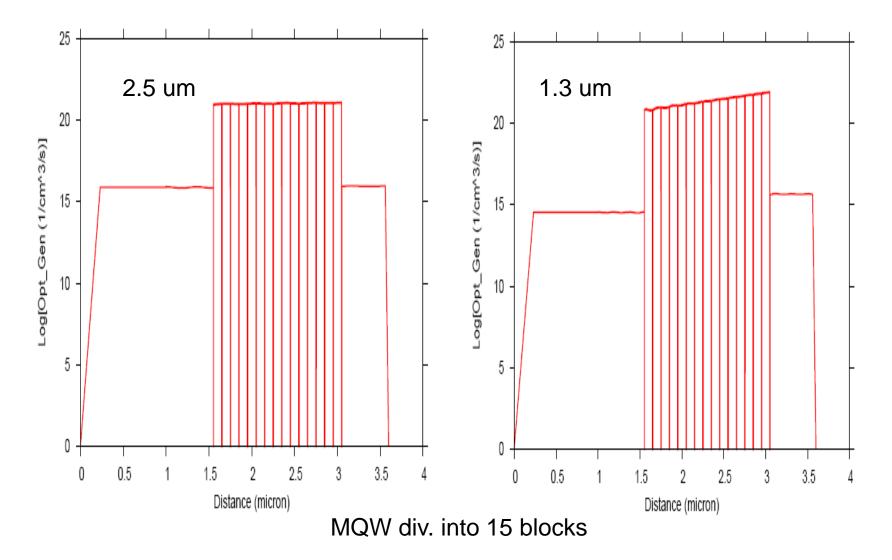






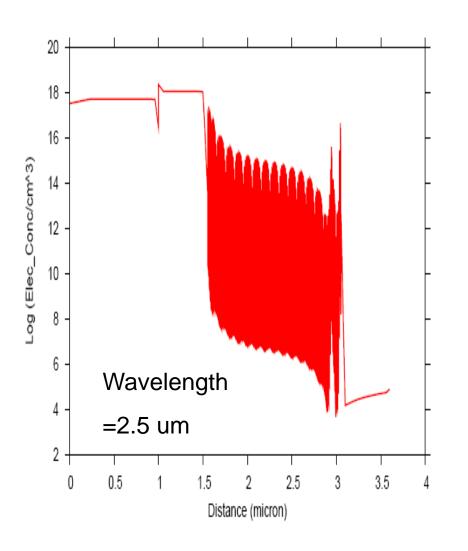


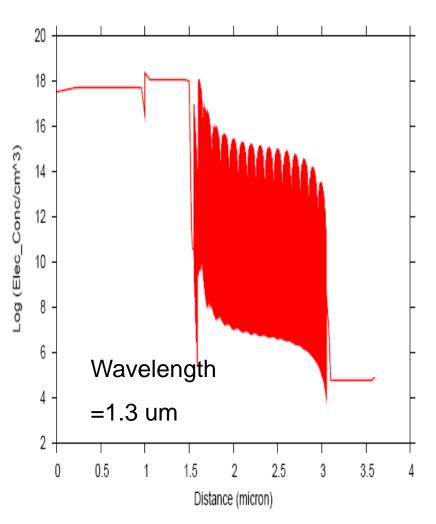
Type-II QWPD: optical generation





Type-II QWPD: electron concentration

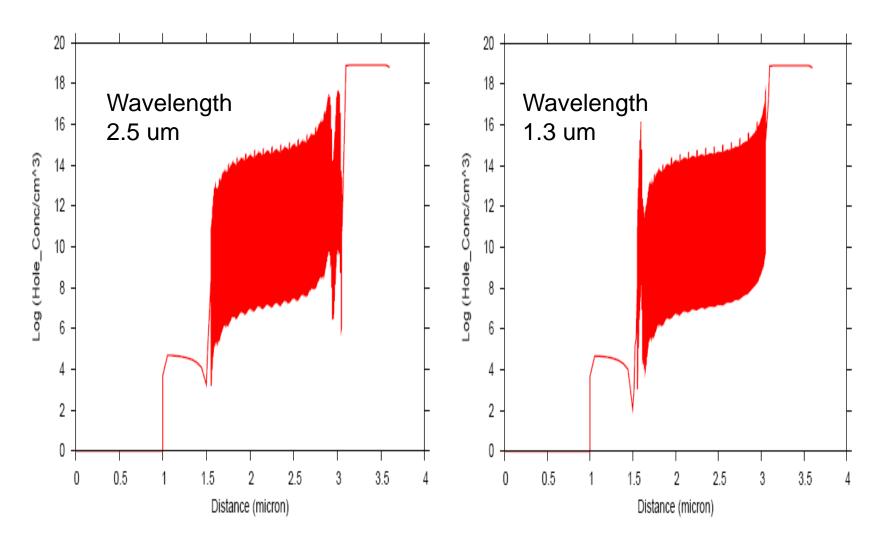








Type-II QWPD: hole concentration







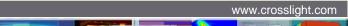
Discussions

PD response as a function of wavelength depends on 3 factors:

- (1) Intrinsic material absorption spectrum;
- (2) Amount and location of absorption for different wavelengths;
- (3) Miniband transport and optical generation

Dark current originated from spontaneous recombination which dominates the tunnelling current at dark.





Summary

Crosslight software ready with

- (1) Accurate computation of minibands of type-II MQW.
- (2) Prediction of material optical absorption spectrum and spontaneous recombination rate as a cause of dark current.
- (3) Non-local transport of tunnelling current based on quantum mechanical calculation taking into account local optical generation rates.

Crosslight model demonstrated through a typical type-II MQW PD with results consistent with experimental measurements.



A Glimpse

Crosslight Software

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- Customer list extends to hundreds of companies, research institutions and universities world wide.
- Originally licensed from the National Research Council Canada and later from Stanford University
- Complete product portfolio for 2D/3D semiconductor device simulation
- Café-time Simulator. Windows based, user friendly graphic user interface makes simulation more enjoyable.



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